Unconventional bulk superconductivity in YFe2Ge2 single crystals

Chen, Jiasheng, Gamza, Monika, Banda, Jacintha, Murphy, Keiron, Tarrant, James, Brando, Manuel and Grosche, F. Malte

Available at http://clok.uclan.ac.uk/35836/


It is advisable to refer to the publisher’s version if you intend to cite from the work.

For more information about UCLan’s research in this area go to http://www.uclan.ac.uk/researchgroups/ and search for <name of research Group>.

For information about Research generally at UCLan please go to http://www.uclan.ac.uk/research/

All outputs in CLoK are protected by Intellectual Property Rights law, including Copyright law. Copyright, IPR and Moral Rights for the works on this site are retained by the individual authors and/or other copyright owners. Terms and conditions for use of this material are defined in the http://clok.uclan.ac.uk/policies/
Unconventional Bulk Superconductivity in YFe$_2$Ge$_2$ Single Crystals

Jiasheng Chen$^{1,}$*, Monika B. Gamza$^2$, Jacinta Banda$^3$, Keiron Murphy$^{1,}$*, James Tarrant$^1$, Manuel Brando$^3$, and F. Malte Grosche$^1$

$^1$Cavendish Laboratory, University of Cambridge, Cambridge CB3 0HE, United Kingdom
$^2$Jeremiah Horrocks Institute for Mathematics, Physics and Astronomy, University of Central Lancashire, PR1 2HE Preston, United Kingdom
$^3$Max Planck Institute for Chemical Physics of Solids, Nöthnitzer Straße 40, 01187 Dresden, Germany

(Received 28 July 2020; revised 17 September 2020; accepted 9 October 2020; published 30 November 2020)

Sharp superconducting transition anomalies observed in a new generation of single crystals establish that bulk superconductivity is intrinsic to high purity YFe$_2$Ge$_2$. Low temperature heat capacity measurements suggest a disorder and field dependent residual Sommerfeld coefficient, consistent with disorder-induced in-gap states as expected for a sign-changing order parameter. The sevenfold reduction in disorder scattering in these new crystals to residual resistivities $\approx 0.45 \, \mu\Omega \cdot \text{cm}$ was achieved using a new liquid transport growth technique, paving the way for multiprobe experiments investigating the normal and superconducting states of YFe$_2$Ge$_2$.

DOI: 10.1103/PhysRevLett.125.237002

The iron-based layered compound YFe$_2$Ge$_2$ has been reported as a new unconventional superconductor [1], which differs from other iron-based superconductors [2] by its lack of group-V (pnictogen) or group-VI (chalcogen) elements and its more three dimensional Fermi surface geometry [3,4]. Nevertheless, YFe$_2$Ge$_2$ shares key properties of the alkali metal iron arsenides, (K/Rb/Cs)$_x$Fe$_2$As$_2$: (i) a similarly enhanced Sommerfeld coefficient, $C/T \sim 100 \, \text{mJ/mole} \cdot \text{K}^2$ [5–8]; (ii) bad metal behavior at room temperature, with resistivity $\rho$ of order 200 $\mu\Omega \cdot \text{cm}$ [9]; and (iii) a strong suppression of the superconducting transition temperature $T_c$ by disorder scattering [10]. The highly correlated low temperature state and its crossover to incoherent bad metal behavior at high temperature [11–13] have been attributed to Hund’s coupling, which forces the iron d electrons into a high spin state, causing significant quasiparticle mass enhancement independently of the shape of the Fermi surface [14]. Initially, no heat capacity anomalies were observed at the superconducting transition in polycrystals [15] or single crystals [16], casting doubt on the intrinsic nature of superconductivity in YFe$_2$Ge$_2$. Further, systematic improvements of polycrystal quality produced the first thermodynamic evidence of superconductivity in YFe$_2$Ge$_2$ [17], clarified the primary origin of crystalline imperfections in YFe$_2$Ge$_2$, and demonstrated that disorder rapidly suppresses the transition at a rate commensurate with expectations for a sign-changing order parameter [18]. This motivated renewed efforts to produce bulk superconducting single crystals, which are required for detailed experiments probing the strongly correlated normal state and the superconducting gap symmetry in YFe$_2$Ge$_2$.

Here, we report that improved YFe$_2$Ge$_2$ crystals display sharp signatures of the superconducting transition in heat capacity, magnetization, and resistivity, proving that superconductivity is indeed intrinsic to YFe$_2$Ge$_2$ of sufficient quality. We find that the size of the superconducting heat capacity anomaly and the extrapolated residual Sommerfeld ratio $\gamma_0 = \lim_{T \to 0} C/T$ correlate strongly with the disorder level and that $\gamma_0$ displays a further, distinct magnetic field dependence. Our findings are consistent with unconventional superconductivity with a sign-changing gap function. This advance is facilitated by modified flux growth techniques that produce YFe$_2$Ge$_2$ single crystals of superior quality, with residual resistivity $\rho_0 < 0.45 \, \mu\Omega \cdot \text{cm}$ and residual resistance ratio RRR = $\rho(300 \, \text{K})/\rho_0 \approx 430$, establishing horizontal liquid transport as a powerful method for producing ultrahigh quality crystals of challenging materials.

Methods.—Our crystal growth experiments are designed to enhance Fe occupancy on the Fe site, which in polycrystals proved to be the determining factor for achieving low disorder [18]. A comprehensive crystal growth study using the conventional Sn-flux method demonstrated that lowering the growth temperatures leads to higher quality [16]. This has motivated our approach, which reduces the temperature at which crystals precipitate from the melt by increasing the effective flux-to-charge ratio. Multiple batches of YFe$_2$Ge$_2$ single crystals have been grown with Sn-flux methods using (i) standard flux growth (SF) as described in [19] and used in previous crystal growth studies on YFe$_2$Ge$_2$ [5,16], (ii) modified flux growth (MF) from a polycrystalline YFe$_2$Ge$_2$ precursor with a reduced peak temperature between 850 and 1150°C, or (iii) horizontal flux or “liquid transport” (LT) growth across a temperature gradient in a two-zone furnace with the cold end at 500°C [20], a relatively little used technique that has
recently been put forward primarily for its higher crystal yield [26]. The advantages of LT and MF growth versus SF growth are discussed below. The in-plane electrical resistance was determined using a standard four-terminal ac technique in a Quantum Design Physical Properties Measurement System to < 0.4 K. Data were scaled to match the published resistivity of 190 μΩ cm at 300 K [5]. Heat capacity measurements employed the pulse-relaxation method in a Quantum Design Physical Properties Measurement System to below 0.4 K and a compensated heat pulse method in a 3He/4He dilution fridge to 50 mK [27]. The magnetization data were taken in a Cryogenic SQUID magnetometer to below 0.45 K and were corrected for the effect of demagnetizing fields by approximating the sample shape as a rectangular prism. Powder XRD patterns were collected at room temperature in the Bragg–Brentano geometry with Cu Kα radiation at 40 kV and 40 mA on a Bruker D8 diffractometer equipped with a Lynxeye XE detector to reduce the effects of Fe fluorescence and Kβ radiation. Refinements of the powder patterns showed no evidence of secondary phases except for occasional Sn-flux inclusions. Lattice parameters were determined by referring to an internal Ge standard and using the Le Bail method.

Low-temperature heat capacity and electrical resistivity of YFe2Ge2 crystals from different growth batches are compared in Fig. 1. Crystals grown using standard flux methods have extrapolated $T = 0$ residual resistivity $\rho_0 \approx 3.5 \mu\Omega\text{cm}$, corresponding to RRR $\approx 50–60$. Some of these samples show resistive transitions, but none displays a superconducting heat capacity anomaly, confirming the findings of the previous single crystal study [16]. The modified flux growth from polycrystal precursors leads to a marked improvement, reaching $\rho_0 \approx 1 \mu\Omega\text{cm}$ and RRR $\approx 200$ in the best batches. These samples show full resistive transitions, which often split into two steps, and they show broad heat capacity anomalies similar to those observed in the best polycrystals with similar RRR values [17,18]. Crystals grown in the liquid transport setup with a horizontal temperature gradient display the lowest residual resistivity $\rho_0 \approx 0.45 \mu\Omega\text{cm}$ and reach resistance ratios of up to RRR $\approx 430$. These samples show sharp heat capacity jumps at a bulk $T_c$ of about 1.1 K.

Resistive, thermodynamic, and magnetic signatures of the superconducting transition in YFe2Ge2 in MF and LT samples are compared in Fig. 2. An applied magnetic field of 2.5 T completely suppresses the superconducting heat capacity anomaly in both YFe2Ge2 samples [Figs. 2(c) and 2(d)], revealing the same underlying normal-state $C/T \approx 100 \text{mJ/molK}^2$. The heat capacity jump $\Delta C(T_c)/T_c$ of $\sim 40%$ of the normal-state Sommerfeld coefficient $\gamma_n \approx 100 \text{mJ/molK}^2$ observed

![FIG. 1. Sommerfeld ratio of the heat capacity $C/T$ (upper panel) and electrical resistivity (lower panel) of YFe2Ge2 single crystals from different growth batches. SF = standard flux growth, MF = modified flux growth, LT = liquid transport growth. These samples show a wide variation in their heat capacity superconducting anomaly, resistive transition, and residual resistivity. Lower residual resistivities correlate with sharper superconducting heat capacity anomalies.](http://example.com/fig1)

![FIG. 2. Superconducting transition signatures for two high-quality batches of YFe2Ge2 samples. [(a),(b)] Electrical resistivity $\rho$, [(c),(d)] Sommerfeld coefficient of the heat capacity $C/T$, [(e),(f)] magnetization (FC = field cooled, ZFC = zero – field cooled). The vertical dash-dotted lines denote the temperatures at which resistivity drops to zero in (a) and (b). The vertical dashed lines indicate the peaks of $C/T$ in (c) and (d).](http://example.com/fig2)
in the highest quality batch LT-A [Figs. 2(d) and 3] falls well below \( \Delta C(T)/T_c \approx 1.43 \gamma_n \) expected in a conventional \( s \)-wave superconductor but is close to that observed in the isostructural compound KFe\(_2\)As\(_2\) [6]. SQUID magnetometry provides further evidence of bulk superconductivity in samples with RRR \( \gtrsim 150 \). The zero-field-cooled diamagnetic response in Figs. 2(e) and 2(f) approaches 100% just below the peak of the specific heat transition for samples from batch MF-D and LT-A, respectively. The field-cooled diamagnetic screening is of order 30%, similar to or larger than values customarily found in other bulk superconducting type-II superconductors (e.g., [28]). Low temperature heat capacity measurements probe the superconducting state more closely (Fig.3). Extrapolating the linear temperature dependence further as the applied field is increased (inset to Fig.3). The magnitude of \( \gamma_0 \approx 0.4 \gamma_n \) at zero field, which rises further as the applied field is increased (inset to Fig. 3). The magnitude of \( \gamma_0/\gamma_n \) as well as its field dependence are similar to observations in some other iron-based superconductors (e.g., [29]). The diamagnetic screening and the sharp heat capacity jump at the transition both suggest 100% bulk superconductivity in the highest quality samples. This is consistent with the mean free path \( \ell \) and the scattering rate \( \tau^{-1} \) extracted from resistivity measurements, using the approach described in [18]: the residual resistivity \( \rho_0 \approx 0.45 \mu \Omega \cdot \text{cm} \) of LT-grown crystals translates to \( \ell \approx 2400 \AA \), far larger than the coherence length \( \xi \approx 180 \AA \) [17], and to \( \tau^{-1} \approx 0.09 \) meV/\( \hbar \), well below the threshold of about 0.2 meV expected within the Abrikosov–Gorkov approach [18,30] from the bulk \( T_c \). The suppressed jump height and residual Sommerfeld coefficient in heat capacity measurements could alternatively result from strong inhomogeneity of composition or disorder level, producing a large nonsuperconducting fraction [2]. Such a scenario is difficult to reconcile with the uniform and high RRR values of all LT crystals extracted from a given batch and with the sharp heat capacity jump, all of which would require a very specific inhomogeneity profile. Spectroscopic studies such as NMR or \( \mu \)SR will be needed to determine the superconducting volume fraction unambiguously.

We now consider the role of crystal growth methodology in producing high-quality crystals (Fig. 4). Structural refinement of XRD data confirms an observation previously made in polycrystals [18], namely that improved crystal quality correlates with increasing \( c \)-axis lattice parameters (Fig. 5). This is consistent with Fe deficiency on the Fe site presenting the dominant source of disorder. This interpretation is further supported by single-crystal XRD at 100 K, which identifies significant Ge substitution on the Fe site in the sample with the lowest RRR and \( c \)-axis lattice parameter (Batch SF-B) [20], whereas bulk superconducting samples showed no signs of Ge-Fe site disorder.

In standard flux growth, all elements are fully dissolved before crystals are formed on cooling. To achieve a high yield, this requires a low flux-to-charge ratio, which in turn leads to a high peak temperature, usually about 1200°C, and a high precipitation temperature. The schematic phase diagram in Fig. 6 illustrates the benefits of our alternative.

**FIG. 3.** Electronic contribution to the specific heat capacity versus temperature, \( C_{el}/T \), of a YFe\(_2\)Ge\(_2\) single crystal from batch LT-A. Applied fields are 0 T (labeled), 0.1 T (red), 0.2 T (green), 0.35 T (black), 0.5 T (pink), 0.7 T (labeled), and 1 T (dark green). \( C_{el} \) is obtained by subtracting from the total specific heat capacity the fitted nuclear contribution \( C_n(H,T) = \alpha(H)/T^2 \) [20]. Inset: extrapolated zero-temperature residual \( C_{el}/T \) versus applied field.

**FIG. 4.** YFe\(_2\)Ge\(_2\) single crystals produced using (a) SF, (b) MF, and (c) LT methods on millimeter-scale paper. Dendrite formation is observed in the SF-grown crystals, which usually contain only one well defined facet along the [100] \( a \) axis in each crystal. Crystals from the MF batches display less obvious dendritic patterns, smoother surfaces, and more rectangular shapes. Both the SF- and MF-grown crystals form thin plates, whereas those from the LT batch are bulkier in the [001] \( c \) direction with thickness reaching up to 2 mm. (d) Schematic illustration of the LT technique.
growth protocols. We attribute the difficulties in growing high-quality YFe$_2$Ge$_2$ crystals by the SF method to (i) the formation of secondary phases such as YFe$_2$Ge$_6$ at $T > 1000$ °C, which affects the composition of the melt, and (ii) the position of the apex of the narrow YFe$_2$Ge$_2$ homogeneity range at a slightly off-stoichiometric composition YFe$_{2-\delta}$Ge$_{2+\delta}$, which favors Fe-poor crystals precipitating at high temperatures. In the modified flux method, the peak temperature can be reduced well below $\sim$1000 °C, while maintaining stoichiometry in the melt thanks to the polycrystalline precursor. Because the precursor is not fully dissolved, the melt remains a saturated solution of YFe$_2$Ge$_2$ in Sn. The melt composition follows the liquidus curve from point A to point B as it heats up, gradually dissolving more of the charge. As the melt is cooled back down, it tracks the liquidus in reverse toward point C while precipitating YFe$_{2-\delta}$Ge$_{2+\delta}$ (0 < $\delta$ < 0.5). This process limits the crystal growth to the desired low temperature region of the liquidus in the complex quaternary phase diagram, avoiding the formation of secondary phases and facilitating the growth of crystals with a higher Fe:Ge ratio, closer to the stoichiometric composition. The heating and cooling cycle $C \rightarrow B \rightarrow C$ can be repeated to increase yield: every heating segment preferentially dissolves small crystallites on the polycrystalline charge, whereas each cooling segment preferentially deposits onto larger crystals forming elsewhere in the crucible. YFe$_2$Ge$_2$ is thereby gradually transported from the polycrystal precursor toward the single crystals, keeping the desired stoichiometry intact. Using Fe-rich precursors may further encourage high Fe content in the crystals. However, because precipitation occurs over a range of temperatures, the resulting crystals exhibit some inhomogeneity of composition and disorder level, causing broad resistive and heat capacity anomalies. Liquid transport growth extends the idea of using the flux to transport material from precursor toward crystals to a horizontal geometry. Maintaining a constant temperature at the cold end of the flux mixture ensures that crystal growth takes place at a fixed point on the liquidus. This improves homogeneity and reduces Fe-Ge site disorder, resulting in the sharpened bulk transition in crystals from Batch LT-A.

Liquid transport growth has produced a sevenfold reduction in disorder level in the new generation of YFe$_2$Ge$_2$ crystals, which, for the first time, show sharp thermodynamic transition anomalies indicative of bulk superconductivity. It thereby emerges as a powerful tool for growing ultrapure crystals of YFe$_2$Ge$_2$ and other challenging materials. Our findings mirror key results in iron arsenides such as (Ba/K)Fe$_2$As$_2$ [6,31]. The fast suppression of bulk superconductivity by lattice disorder excludes a conventional isotropic s-wave scenario. The small $\Delta C(T)/\gamma_0 T_c$ can be ascribed to multigap superconductivity, as in KFe$_2$As$_2$ [6,31]. Likewise, the significant extrapolated residual Sommerfeld ratio $\gamma_0$ might point toward a further downturn in $C_{\text{pol}}/T$ at temperatures below the range of our current experiments if the gap on part of the Fermi surface is much smaller than $k_B T_c$. However, because $\gamma_0$ rises with increasing disorder level, it is more...
plausibly attributed to impurity-induced states within the gap: for sign-changing order parameters, e.g., a two-band $s^{±}$ order parameter, a finite $\gamma_0$ at zero field and a linear temperature dependence of $C/T$ at low $T$—as observed in YFe$_2$Ge$_2$ (Fig. 3)—are expected when the level of impurity scattering increases above a critical threshold [32]. The field dependence of $\gamma_0$ is also consistent with this scenario [33,34], which is in line with earlier theoretical predictions [3] for YFe$_2$Ge$_2$.

All data needed to evaluate the conclusions in the paper are present in the paper, the Supplementary Materials, and the Data Repository at the University of Cambridge and can be downloaded from [35].

We thank, in particular, N. Halcovitch for assistance with single-crystal XRD, and A. Chubukov, C. Geibel, G. Lonzarich, J. Schmalian, F. Steglich, and M. Sutherland for helpful discussions. The work was supported by the EPSRC of the UK (Grants No. EP/K012894/1 and No. EP/P023290/1) and by Trinity College.

[Corresponding author.]
jc732@cam.ac.uk

[Present address: Clarendon Laboratory, Department of Physics, University of Oxford, Oxford OX1 3PU, United Kingdom.]


[15] I. Felner, B. Lv, K. Zhao, and C. W. Chu, High-pressure resistivity of YFe$_2$Si$_2$ and magnetic studies of Y$_{1−x}$Ho$_x$Fe$_2$Si$_2$ and Y$_{2−x}$Si$_2$Fe$_2$Si$_2$ systems, J. Supercond. Novel Magn. 28, 1207 (2015).


[35] https://doi.org/10.17863/CAM.59394.